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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	RL78
Core Size	16-Bit
Speed	24MHz
Connectivity	CSI, I <sup>2</sup> C, LINbus, UART/USART
Peripherals	DMA, LCD, LVD, POR, PWM, WDT
Number of I/O	42
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 9x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (12x12)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10wlaafa-30">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10wlaafa-30</a>

**Absolute Maximum Ratings (2/3)**

Parameter	Symbol	Conditions	Ratings	Unit
LCD voltage	V <sub>L1</sub>	V <sub>L1</sub> voltage <sup>Note 1</sup>	-0.3 to +2.8 and -0.3 to V <sub>L4</sub> +0.3	V
	V <sub>L2</sub>	V <sub>L2</sub> voltage <sup>Note 1</sup>	-0.3 to V <sub>L4</sub> +0.3 <sup>Note 2</sup>	V
	V <sub>L3</sub>	V <sub>L3</sub> voltage <sup>Note 1</sup>	-0.3 to V <sub>L4</sub> +0.3 <sup>Note 2</sup>	V
	V <sub>L4</sub>	V <sub>L4</sub> voltage <sup>Note 1</sup>	-0.3 to +6.5	V
	V <sub>LCAP</sub>	CAPL, CAPH voltage <sup>Note 1</sup>	-0.3 to V <sub>L4</sub> +0.3 <sup>Note 2</sup>	V
	V <sub>OUT</sub>	COM0 to COM7 SEG0 to SEG50 output voltage	External resistance division method	-0.3 to V <sub>DD</sub> +0.3 <sup>Note 2</sup>
			Capacitor split method	-0.3 to V <sub>DD</sub> +0.3 <sup>Note 2</sup>
			Internal voltage boosting method	-0.3 to V <sub>L4</sub> +0.3 <sup>Note 2</sup>

**Notes 1.** This value only indicates the absolute maximum ratings when applying voltage to the V<sub>L1</sub>, V<sub>L2</sub>, V<sub>L3</sub>, and V<sub>L4</sub> pins; it does not mean that applying voltage to these pins is recommended. When using the internal voltage boosting method or capacitance split method, connect these pins to V<sub>SS</sub> via a capacitor (0.47  $\mu$ F  $\pm$  30%) and connect a capacitor (0.47  $\mu$ F  $\pm$  30%) between the CAPL and CAPH pins.

**2.** Must be 6.5 V or lower.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remark** V<sub>SS</sub>: Reference voltage

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output current, low <sup>Note 1</sup>	I <sub>OL1</sub>	Per pin for P00 to P07, P10 to P17, P22 to P27, P30 to P35, P40 to P47, P50 to P57, P70 to P77, P125 to P127, P130			20.0 <sup>Note 2</sup>	mA
		Per pin for P60 and P61			15.0 <sup>Note 2</sup>	mA
		Total of P40 to P47, P130 (When duty = 70% <sup>Note 3</sup> )	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V		70.0	mA
			2.7 V ≤ V <sub>DD</sub> < 4.0 V		15.0	mA
			1.8 V ≤ V <sub>DD</sub> < 2.7 V		9.0	mA
			1.6 V ≤ V <sub>DD</sub> < 1.8 V		4.5	mA
		Total of P00 to P07, P10 to P17, P22 to P27, P30 to P35, P50 to P57, P70 to P77, P125 to P127 (When duty = 70% <sup>Note 3</sup> )	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V		90.0	mA
			2.7 V ≤ V <sub>DD</sub> < 4.0 V		35.0	mA
			1.8 V ≤ V <sub>DD</sub> < 2.7 V		20.0	mA
			1.6 V ≤ V <sub>DD</sub> < 1.8 V		10.0	mA
		Total of all pins (When duty = 70% <sup>Note 3</sup> )			160.0	mA
	I <sub>OL2</sub>	Per pin for P20 and P21			0.4 <sup>Note 2</sup>	mA
		Total of all pins (When duty = 70% <sup>Note 3</sup> )	1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V		0.8	mA

**Notes** 1. Value of the current at which the device operation is guaranteed even if the current flows from an output pin to the V<sub>SS</sub> pin

2. Do not exceed the total current value.

3. Output current value under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (I<sub>OL</sub> × 0.7)/(n × 0.01)

<Example> Where n = 80% and I<sub>OL</sub> = 70.0 mA

$$\text{Total output current of pins} = (70.0 \times 0.7)/(80 \times 0.01) \cong 61.25 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output voltage, high	$V_{OH1}$	P00 to P07, P10 to P17, P22 to P27, P30 to P35, P40 to P47, P50 to P57, P70 to P77, P125 to P127, P130	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OH1} = -10.0\text{ mA}$	$V_{DD} - 1.5$		V
			$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OH1} = -3.0\text{ mA}$	$V_{DD} - 0.7$		V
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OH1} = -2.0\text{ mA}$	$V_{DD} - 0.6$		V
			$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OH1} = -1.5\text{ mA}$	$V_{DD} - 0.5$		V
			$1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OH1} = -1.0\text{ mA}$	$V_{DD} - 0.5$		V
	$V_{OH2}$	P20 and P21	$1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OH2} = -100\text{ }\mu\text{A}$	$V_{DD} - 0.5$		V
Output voltage, low	$V_{OL1}$	P00 to P07, P10 to P17, P22 to P27, P30 to P35, P40 to P47, P50 to P57, P70 to P77, P125 to P127, P130	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OL1} = 20\text{ mA}$		1.3	V
			$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OL1} = 8.5\text{ mA}$		0.7	V
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OL1} = 3.0\text{ mA}$		0.6	V
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OL1} = 1.5\text{ mA}$		0.4	V
			$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OL1} = 0.6\text{ mA}$		0.4	V
			$1.6\text{ V} \leq V_{DD} < 1.8\text{ V}$ , $I_{OL1} = 0.3\text{ mA}$		0.4	V
	$V_{OL2}$	P20 and P21	$1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OL2} = 400\text{ }\mu\text{A}$		0.4	V
	$V_{OL3}$	P60 and P61	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OL3} = 15.0\text{ mA}$		2.0	V
			$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OL3} = 5.0\text{ mA}$		0.4	V
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OL3} = 3.0\text{ mA}$		0.4	V
			$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OL3} = 2.0\text{ mA}$		0.4	V
			$1.6\text{ V} \leq V_{DD} < 1.8\text{ V}$ , $I_{OL3} = 1.0\text{ mA}$		0.4	V

**Caution** P00, P04 to P07, P16, P17, P35, P42 to P44, P46, P47, P53 to P56, and P130 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## 2.3.2 Supply current characteristics

 $(T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V})$ 

(1/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	$I_{DD1}$	Operating mode	HS (high-speed main) mode <sup>Note 5</sup>	$f_{HOCO} = 48\text{ MHz}^{\text{Note 3}}$ , $f_{IH} = 24\text{ MHz}^{\text{Note 3}}$	Basic operation	$V_{DD} = 5.0\text{ V}$	2.0		mA
						$V_{DD} = 3.0\text{ V}$	2.0		mA
					Normal operation	$V_{DD} = 5.0\text{ V}$	3.8	6.5	mA
						$V_{DD} = 3.0\text{ V}$	3.8	6.5	mA
				$f_{HOCO} = 24\text{ MHz}^{\text{Note 3}}$ , $f_{IH} = 24\text{ MHz}^{\text{Note 3}}$	Basic operation	$V_{DD} = 5.0\text{ V}$	1.7		mA
						$V_{DD} = 3.0\text{ V}$	1.7		mA
					Normal operation	$V_{DD} = 5.0\text{ V}$	3.6	6.1	mA
						$V_{DD} = 3.0\text{ V}$	3.6	6.1	mA
				$f_{HOCO} = 16\text{ MHz}^{\text{Note 3}}$ , $f_{IH} = 16\text{ MHz}^{\text{Note 3}}$	Normal operation	$V_{DD} = 5.0\text{ V}$	2.7	4.7	mA
						$V_{DD} = 3.0\text{ V}$	2.7	4.7	mA
			LS (low-speed main) mode <sup>Note 5</sup>	$f_{HOCO} = 8\text{ MHz}^{\text{Note 3}}$ , $f_{IH} = 8\text{ MHz}^{\text{Note 3}}$	Normal operation	$V_{DD} = 3.0\text{ V}$	1.2	2.1	mA
						$V_{DD} = 2.0\text{ V}$	1.2	2.1	mA
			LV (low-voltage main) mode <sup>Note 5</sup>	$f_{HOCO} = 4\text{ MHz}^{\text{Note 3}}$ , $f_{IH} = 4\text{ MHz}^{\text{Note 3}}$	Normal operation	$V_{DD} = 3.0\text{ V}$	1.2	1.8	mA
						$V_{DD} = 2.0\text{ V}$	1.2	1.8	mA
			HS (high-speed main) mode <sup>Note 5</sup>	$f_{MX} = 20\text{ MHz}^{\text{Note 2}}$ , $V_{DD} = 5.0\text{ V}$	Normal operation	Square wave input	3.0	5.1	mA
						Resonator connection	3.2	5.2	mA
				$f_{MX} = 20\text{ MHz}^{\text{Note 2}}$ , $V_{DD} = 3.0\text{ V}$	Normal operation	Square wave input	2.9	5.1	mA
						Resonator connection	3.2	5.2	mA
				$f_{MX} = 16\text{ MHz}^{\text{Note 2}}$ , $V_{DD} = 5.0\text{ V}$	Normal operation	Square wave input	2.5	4.4	mA
						Resonator connection	2.7	4.5	mA
				$f_{MX} = 16\text{ MHz}^{\text{Note 2}}$ , $V_{DD} = 3.0\text{ V}$	Normal operation	Square wave input	2.5	4.4	mA
						Resonator connection	2.7	4.5	mA
				$f_{MX} = 10\text{ MHz}^{\text{Note 2}}$ , $V_{DD} = 5.0\text{ V}$	Normal operation	Square wave input	1.9	3.0	mA
						Resonator connection	1.9	3.0	mA
				$f_{MX} = 10\text{ MHz}^{\text{Note 2}}$ , $V_{DD} = 3.0\text{ V}$	Normal operation	Square wave input	1.9	3.0	mA
						Resonator connection	1.9	3.0	mA
			LS (low-speed main) mode <sup>Note 5</sup>	$f_{MX} = 8\text{ MHz}^{\text{Note 2}}$ , $V_{DD} = 3.0\text{ V}$	Normal operation	Square wave input	1.1	2.0	mA
						Resonator connection	1.1	2.0	mA
				$f_{MX} = 8\text{ MHz}^{\text{Note 2}}$ , $V_{DD} = 2.0\text{ V}$	Normal operation	Square wave input	1.1	2.0	mA
						Resonator connection	1.1	2.0	mA
			Subsystem clock operation	$f_{SUB} = 32.768\text{ kHz}^{\text{Note 4}}$ , $T_A = -40^\circ\text{C}$	Normal operation	Square wave input	4.0	5.4	$\mu\text{A}$
						Resonator connection	4.3	5.4	$\mu\text{A}$
				$f_{SUB} = 32.768\text{ kHz}^{\text{Note 4}}$ , $T_A = +25^\circ\text{C}$	Normal operation	Square wave input	4.0	5.4	$\mu\text{A}$
						Resonator connection	4.3	5.4	$\mu\text{A}$
				$f_{SUB} = 32.768\text{ kHz}^{\text{Note 4}}$ , $T_A = +50^\circ\text{C}$	Normal operation	Square wave input	4.1	7.1	$\mu\text{A}$
						Resonator connection	4.4	7.1	$\mu\text{A}$
				$f_{SUB} = 32.768\text{ kHz}^{\text{Note 4}}$ , $T_A = +70^\circ\text{C}$	Normal operation	Square wave input	4.3	8.7	$\mu\text{A}$
						Resonator connection	4.7	8.7	$\mu\text{A}$
				$f_{SUB} = 32.768\text{ kHz}^{\text{Note 4}}$ , $T_A = +85^\circ\text{C}$	Normal operation	Square wave input	4.7	12.0	$\mu\text{A}$
						Resonator connection	5.2	12.0	$\mu\text{A}$

(Notes and Remarks are listed on the next page.)

## 2.5.2 Serial interface IICA

(1) I<sup>2</sup>C standard mode (1/2)(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLA0 clock frequency	f <sub>SCL</sub>	Normal mode: f <sub>CLK</sub> ≥ 1 MHz	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0	100	0	100	0	100	kHz
			1.8 V (2.4 V <sup>Note 3</sup> ) ≤ V <sub>DD</sub> ≤ 5.5 V	0	100	0	100	0	100	kHz
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	—	—	—	—	0	100	kHz
Setup time of restart condition	t <sub>SU:STA</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V		4.7		4.7		4.7		μs
		1.8 V (2.4 V <sup>Note 3</sup> ) ≤ V <sub>DD</sub> ≤ 5.5 V		4.7		4.7		4.7		μs
		1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V		—	—	—	—	4.7		μs
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V		4.0		4.0		4.0		μs
		1.8 V (2.4 V <sup>Note 3</sup> ) ≤ V <sub>DD</sub> ≤ 5.5 V		4.0		4.0		4.0		μs
		1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V		—	—	—	—	4.0		μs
Hold time when SCLA0 = "L"	t <sub>LOW</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V		4.7		4.7		4.7		μs
		1.8 V (2.4 V <sup>Note 3</sup> ) ≤ V <sub>DD</sub> ≤ 5.5 V		4.7		4.7		4.7		μs
		1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V		—	—	—	—	4.7		μs
Hold time when SCLA0 = "H"	t <sub>HIGH</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V		4.0		4.0		4.0		μs
		1.8 V (2.4 V <sup>Note 3</sup> ) ≤ V <sub>DD</sub> ≤ 5.5 V		4.0		4.0		4.0		μs
		1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V		—	—	—	—	4.0		μs

(Notes, Caution and Remark are listed on the next page.)

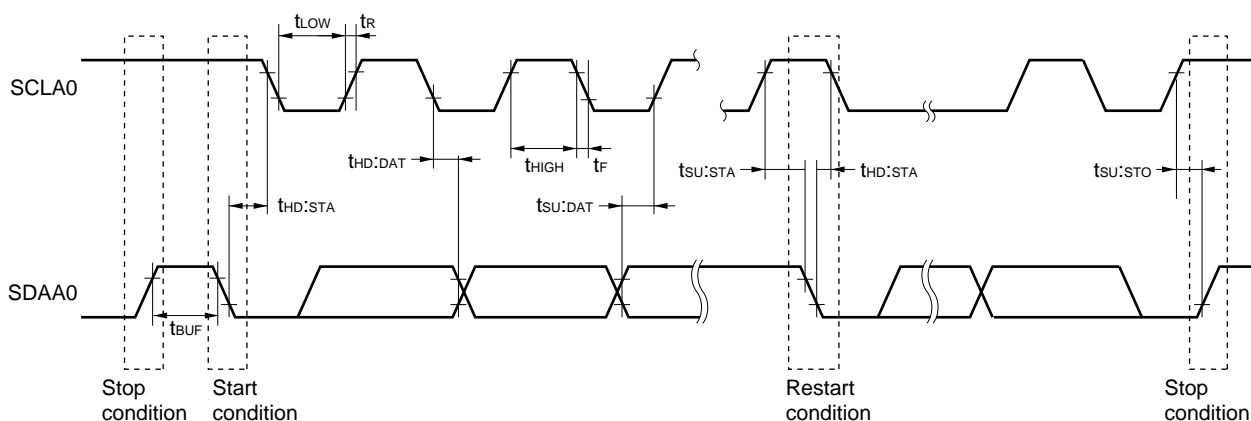
**(3) I<sup>2</sup>C fast mode plus****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLA0 clock frequency	$f_{SCL}$	Fast mode plus: $f_{CLK} \geq 10\text{ MHz}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	0	1000	—	—	—	—	kHz
Setup time of restart condition	$t_{SU:STA}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		0.26		—	—	—	—	$\mu\text{s}$
Hold time <sup>Note 1</sup>	$t_{HD:STA}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		0.26		—	—	—	—	$\mu\text{s}$
Hold time when SCLA0 = "L"	$t_{LOW}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		0.5		—	—	—	—	$\mu\text{s}$
Hold time when SCLA0 = "H"	$t_{HIGH}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		0.26		—	—	—	—	$\mu\text{s}$
Data setup time (reception)	$t_{SU:DAT}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		50		—	—	—	—	ns
Data hold time (transmission) <sup>Note 2</sup>	$t_{HD:DAT}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		0	0.45	—	—	—	—	$\mu\text{s}$
Setup time of stop condition	$t_{SU:STO}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		0.26		—	—	—	—	$\mu\text{s}$
Bus-free time	$t_{BUF}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		0.5		—	—	—	—	$\mu\text{s}$

**Notes** 1. The first clock pulse is generated after this period when the start/restart condition is detected.2. The maximum value (MAX.) of  $t_{HD:DAT}$  is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

**Caution** The values in the above table are applied even when bit 2 (PIOR2) in the peripheral I/O redirection register (PIOR) is 1. At this time, the pin characteristics ( $I_{OH1}$ ,  $I_{OL1}$ ,  $V_{OH1}$ ,  $V_{OL1}$ ) must satisfy the values in the redirect destination.

**Remark** The maximum value of  $C_b$  (communication line capacitance) and the value of  $R_b$  (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode plus:  $C_b = 120\text{ pF}$ ,  $R_b = 1.1\text{ k}\Omega$ **I<sup>2</sup>C serial transfer timing**

(TA = -40 to +105°C, 2.4 V ≤ VDD ≤ 5.5 V, VSS = 0 V)

(2/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit	
Supply current <sup>Note 1</sup>	I <sub>DD2</sub> <sup>Note 2</sup>	HALT mode	HS (high-speed main) mode <sup>Note 7</sup>	f <sub>HOCO</sub> = 48 MHz <sup>Note 4</sup> , f <sub>IH</sub> = 24 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.71	2.55	mA	
					V <sub>DD</sub> = 3.0 V		0.71	2.55	mA	
				f <sub>HOCO</sub> = 24 MHz <sup>Note 4</sup> , f <sub>IH</sub> = 24 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.49	1.95	mA	
					V <sub>DD</sub> = 3.0 V		0.49	1.95	mA	
				f <sub>HOCO</sub> = 16 MHz <sup>Note 4</sup> , f <sub>IH</sub> = 16 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.43	1.50	mA	
					V <sub>DD</sub> = 3.0 V		0.43	1.50	mA	
			HS (high-speed main) mode <sup>Note 7</sup>	f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		0.31	1.76	mA	
					Resonator connection		0.48	1.92	mA	
				f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		0.29	1.76	mA	
					Resonator connection		0.48	1.92	mA	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		0.20	0.96	mA	
					Resonator connection		0.28	1.07	mA	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		0.19	0.96	mA	
					Resonator connection		0.28	1.07	mA	
		Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> , T <sub>A</sub> = −40°C	Square wave input		0.34	0.62	μA		
				Resonator connection		0.51	0.80	μA		
			f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> , T <sub>A</sub> = +25°C	Square wave input		0.38	0.62	μA		
				Resonator connection		0.57	0.80	μA		
			f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> , T <sub>A</sub> = +50°C	Square wave input		0.46	2.30	μA		
				Resonator connection		0.67	2.49	μA		
			f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> , T <sub>A</sub> = +70°C	Square wave input		0.65	4.03	μA		
				Resonator connection		0.91	4.22	μA		
			f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> , T <sub>A</sub> = +85°C	Square wave input		1.00	8.04	μA		
				Resonator connection		1.31	8.23	μA		
		f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> , T <sub>A</sub> = +105°C	Square wave input		3.05	27.00	μA			
			Resonator connection		3.24	27.00	μA			
	I <sub>DD3</sub> <sup>Note 6</sup>	STOP mode <sup>Note 8</sup>	T <sub>A</sub> = −40°C					0.18	0.52	μA
			T <sub>A</sub> = +25°C					0.24	0.52	μA
			T <sub>A</sub> = +50°C					0.33	2.21	μA
			T <sub>A</sub> = +70°C					0.53	3.94	μA
			T <sub>A</sub> = +85°C					0.93	7.95	μA
			T <sub>A</sub> = +105°C					2.91	25.00	μA

(Notes and Remarks are listed on the next page.)



- Notes**
1. Total current flowing into  $V_{DD}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$  or  $V_{SS}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the LCD controller/driver, A/D converter, LVD circuit, comparator, I/O port, on-chip pull-up/pull-down resistors, and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped.  
When  $RTCLPC = 1$  and setting ultra-low current consumption ( $AMPHS1 = 1$ ). The current flowing into the real-time clock 2 is included. The current flowing into the clock output/buzzer output, 12-bit interval timer, and watchdog timer is not included.
  6. The current flowing into the real-time clock 2, clock output/buzzer output, 12-bit interval timer, and watchdog timer is not included.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }24\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
  8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks**
1.  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2.  $f_{HOCO}$ : High-speed on-chip oscillator clock frequency (48 MHz max.)
  3.  $f_{IH}$ : High-speed on-chip oscillator clock frequency (24 MHz max.)
  4.  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
  5. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is  $T_A = 25^{\circ}\text{C}$

**Notes** 1. Current flowing to  $V_{DD}$ .

2. When high speed on-chip oscillator and high-speed system clock are stopped.
3. Current flowing only to the real-time clock 2 (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The value of the current for the RL78 microcontrollers is the sum of the values of either  $I_{DD1}$  or  $I_{DD2}$ , and  $I_{RTC}$ , when the real-time clock 2 operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected,  $I_{FIL}$  should be added.  $I_{DD2}$  subsystem clock operation includes the operational current of real-time clock 2.
4. Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The value of the current for the RL78 microcontrollers is the sum of the values of either  $I_{DD1}$  or  $I_{DD2}$ , and  $I_{TMKA}$ , when the 12-bit interval timer operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected,  $I_{FIL}$  should be added.
5. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{WDT}$  when the watchdog timer operates.
6. Current flowing only to the A/D converter. The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$  or  $I_{DD2}$  and  $I_{ADC}$  when the A/D converter operates in an operation mode or the HALT mode.
7. Current flowing only to the LVD circuit. The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{LVD}$  when the LVD circuit operates.
8. Current flowing only during data flash rewrite.
9. Current flowing only during self programming.
10. For shift time to the SNOOZE mode, see **21.3.3 SNOOZE mode** in the RL78/L13 User's Manual.
11. Current flowing only to the comparator circuit. The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{CMP}$  when the comparator circuit operates.
12. Current flowing only to the LCD controller/driver. The value of the current for the RL78 microcontrollers is the sum of the supply current ( $I_{DD1}$  or  $I_{DD2}$ ) and LCD operating current ( $I_{LCD1}$ ,  $I_{LCD2}$ , or  $I_{LCD3}$ ), when the LCD controller/driver operates in operation mode or HALT mode. However, not including the current flowing into the LCD panel. Conditions of the TYP. value and MAX. value are as follows.
  - Setting 20 pins as the segment function and blinking all
  - Selecting  $f_{SUB}$  for system clock when LCD clock = 128 Hz (LCDC0 = 07H)
  - Setting four time slices and 1/3 bias
13. Not including the current flowing into the external division resistor when using the external resistance division method.

**Remarks** 1.  $f_{IL}$ : Low-speed on-chip oscillator clock frequency

2.  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
3.  $f_{CLK}$ : CPU/peripheral hardware clock frequency
4. The temperature condition for the TYP. value is  $T_A = 25^{\circ}\text{C}$ .

## 3.4 AC Characteristics

(TA =  $-40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

Parameter	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Instruction cycle (minimum instruction execution time)	T <sub>CY</sub>	Main system clock (f <sub>MAIN</sub> ) operation	HS (high-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.0417		1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625		1	μs
		Subsystem clock (f <sub>SUB</sub> ) operation		2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	28.5	30.5	31.3	μs
		In the self programming mode	HS (high-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.0417		1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625		1	μs
External system clock frequency	f <sub>EX</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V			1.0		20.0	MHz
		2.4 V ≤ V <sub>DD</sub> < 2.7 V			1.0		16.0	MHz
	f <sub>EXS</sub>				32		35	kHz
External system clock input high-level width, low-level width	t <sub>EXH</sub> , t <sub>EXL</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V			24			ns
		2.4 V ≤ V <sub>DD</sub> < 2.7 V			30			ns
	t <sub>EXHS</sub> , t <sub>EXLS</sub>				13.7			μs
TI00 to TI07 input high-level width, low-level width	t <sub>TIH</sub> , t <sub>TIL</sub>				1/f <sub>MCK</sub> +10			ns
TO00 to TO07, TKBO00 <sup>Note</sup> , TKBO01-0 to TKBO01-2 <sup>Note</sup> output frequency	f <sub>TO</sub>	HS (high-speed main) mode	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V				12	MHz
			2.7 V ≤ V <sub>DD</sub> < 4.0 V				8	MHz
			2.4 V ≤ V <sub>DD</sub> < 2.7 V				4	MHz
PCLBUZ0, PCLBUZ1 output frequency	f <sub>PCL</sub>	HS (high-speed main) mode	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V				16	MHz
			2.7 V ≤ V <sub>DD</sub> < 4.0 V				8	MHz
			2.4 V ≤ V <sub>DD</sub> < 2.7 V				4	MHz
Interrupt input high-level width, low-level width	t <sub>INTH</sub> , t <sub>INTL</sub>	INTP0 to INTP7		2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	1			μs
Key interrupt input high-level width, low-level width	t <sub>KRH</sub> , t <sub>KRL</sub>	KR0 to KR7		2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	250			ns
IH-PWM output restart input high-level width	t <sub>IHR</sub>	INTP0 to INTP7			2			f <sub>CLK</sub>
TMKB2 forced output stop input high-level width	t <sub>IHR</sub>	INTP0 to INTP2			2			f <sub>CLK</sub>
RESET low-level width	t <sub>RSL</sub>				10			μs

(Note and Remark are listed on the next page.)

**Notes 5.** The smaller maximum transfer rate derived by using  $f_{\text{MCK}}/12$  or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when  $2.4\text{ V} \leq V_{\text{DD}} < 3.3\text{ V}$  and  $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \text{ [bps]}$$

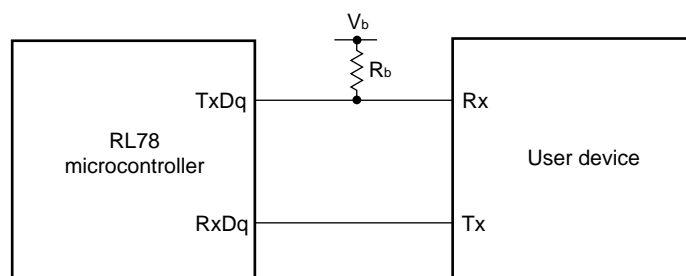
$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

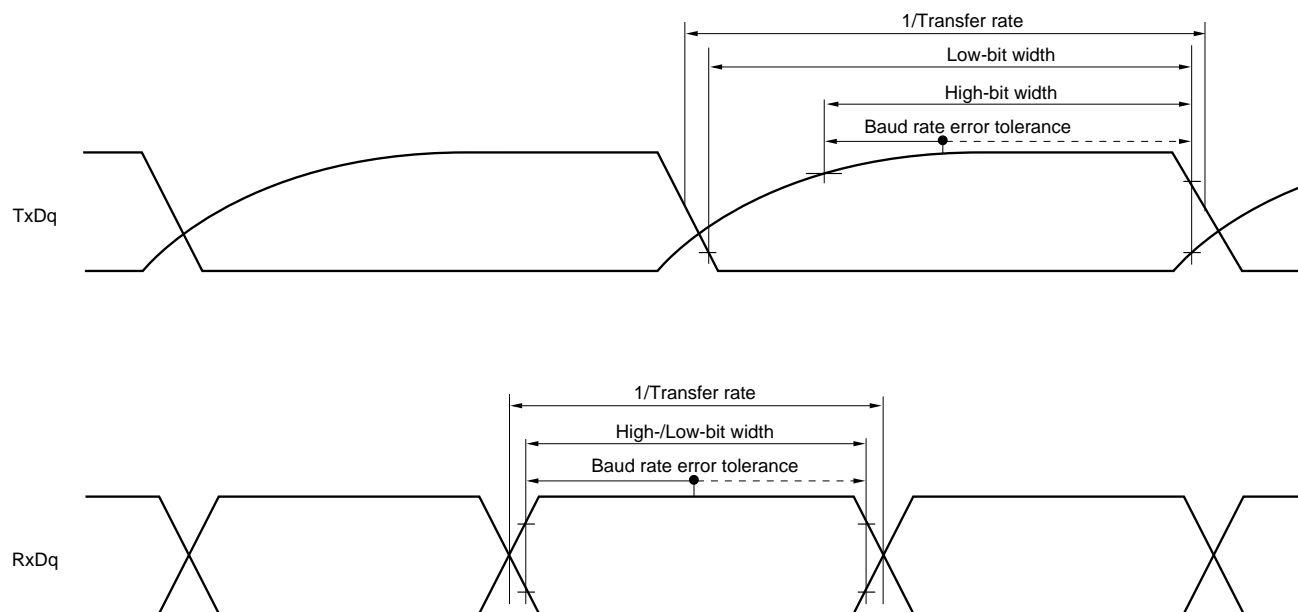
\* This value is the theoretical value of the relative difference between the transmission and reception sides.

6. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to **Note 5** above to calculate the maximum transfer rate under conditions of the customer.

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output ( $V_{\text{DD}}$  tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{\text{IH}}$  and  $V_{\text{IL}}$ , see the DC characteristics with TTL input buffer selected.

**UART mode connection diagram (during communication at different potential)**



**UART mode bit width (during communication at different potential) (reference)**

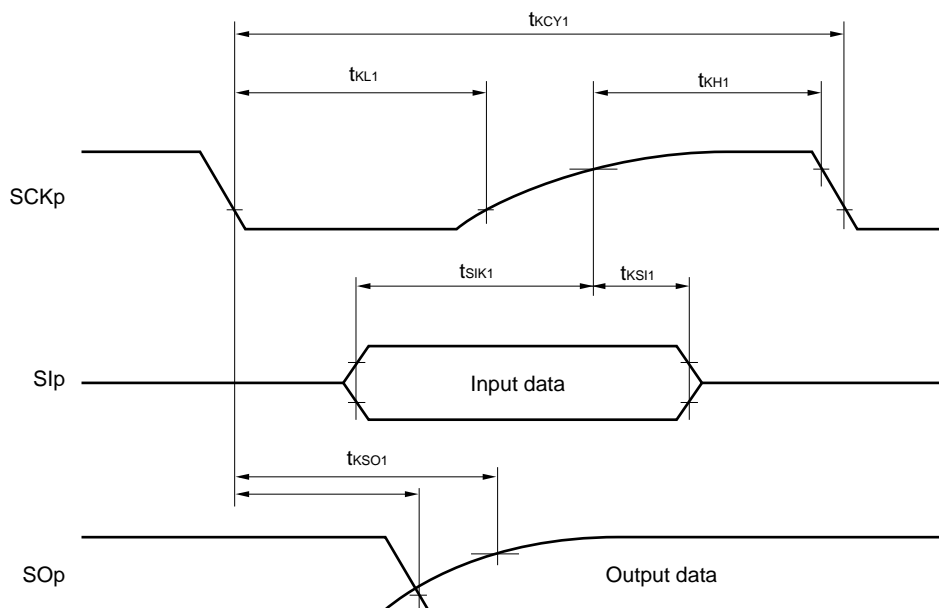
- Remarks**
1.  $R_b[\Omega]$ : Communication line (TxDq) pull-up resistance,  $C_b[\text{F}]$ : Communication line (TxDq) load capacitance,  $V_b[\text{V}]$ : Communication line voltage
  2. q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 3)
  3.  $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  
m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (1/2)**  
**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

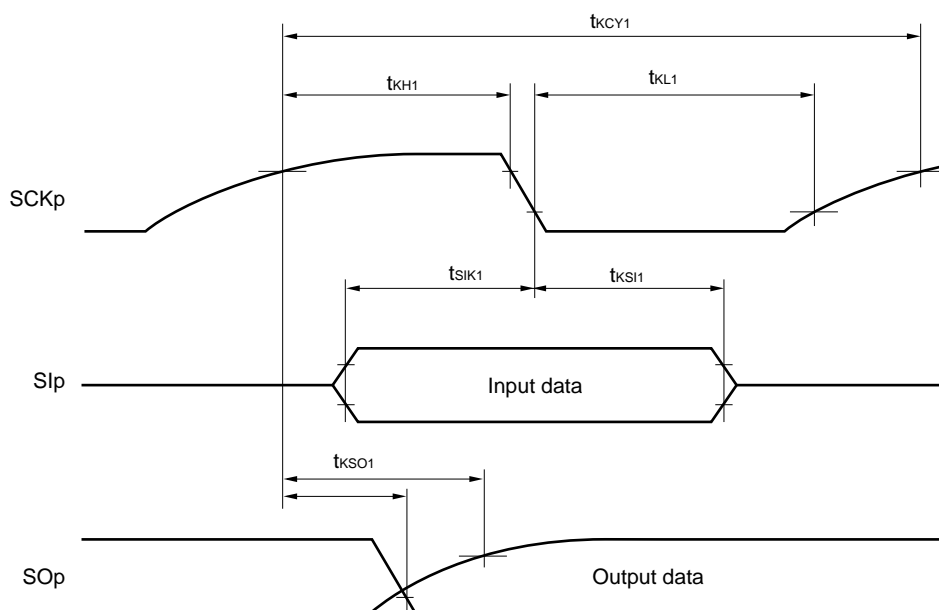
Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCKp cycle time	$t_{KCY1}$	$t_{KCY1} \geq 4/f_{CLK}$ $4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	600		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1000		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 1.8\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	2300		ns
SCKp high-level width	$t_{KH1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	$t_{KCY1}/2 - 150$		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$t_{KCY1}/2 - 340$		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$t_{KCY1}/2 - 916$		ns
SCKp low-level width	$t_{KL1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	$t_{KCY1}/2 - 24$		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$t_{KCY1}/2 - 36$		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$t_{KCY1}/2 - 100$		ns
Slp setup time (to SCKp $\uparrow$ ) <sup>Note 1</sup>	$t_{SIK1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	162		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	354		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	958		ns
Slp hold time (from SCKp $\uparrow$ ) <sup>Note 1</sup>	$t_{SH1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	38		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	38		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	38		ns
Delay time from SCKp $\downarrow$ to SOp output <sup>Note 1</sup>	$t_{KSO1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$		200	ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		390	ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		966	ns

(Note, Caution and Remark are listed on the next page.)

**CSI mode serial transfer timing (master mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (master mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark** p: CSI number (p = 00, 10), m: Unit number, n: Channel number (mn = 00, 02),  
g: PIM and POM number (g = 0, 1)

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode) (1/2)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCLr clock frequency	$f_{SCL}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		400 <sup>Note 1</sup>	kHz
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		400 <sup>Note 1</sup>	kHz
		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$		100 <sup>Note 1</sup>	kHz
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		100 <sup>Note 1</sup>	kHz
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		100 <sup>Note 1</sup>	kHz
Hold time when SCLr = "L"	$t_{LOW}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1200		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1200		ns
		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	4600		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	4600		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	4650		ns
Hold time when SCLr = "H"	$t_{HIGH}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	620		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b < 2.7\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	500		ns
		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	2700		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	2400		ns
		$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	1830		ns

(Notes and Caution are listed on the next page, and Remarks are listed on the page after the next page.)



## 3.6.3 Comparator

**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage range	Ivref		0		$V_{DD} - 1.4$	V
	Ivcmp		-0.3		$V_{DD} + 0.3$	V
Output delay	td	$V_{DD} = 3.0\text{ V}$ Input slew rate $> 50\text{ mV}/\mu\text{s}$	Comparator high-speed mode, standard mode		1.2	$\mu\text{s}$
			Comparator high-speed mode, window mode		2.0	$\mu\text{s}$
			Comparator low-speed mode, standard mode		3.0	$\mu\text{s}$
High-electric-potential reference voltage	VTW+	Comparator high-speed mode, window mode	$0.66V_{DD}$	$0.76V_{DD}$	$0.86V_{DD}$	V
Low-electric-potential reference voltage	VTW-	Comparator high-speed mode, window mode	$0.14V_{DD}$	$0.24V_{DD}$	$0.34V_{DD}$	V
Operation stabilization wait time	t <sub>CMP</sub>		100			$\mu\text{s}$
Internal reference output voltage <sup>Note</sup>	V <sub>BGR</sub>	$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , HS (high-speed main) mode	1.38	1.45	1.50	V

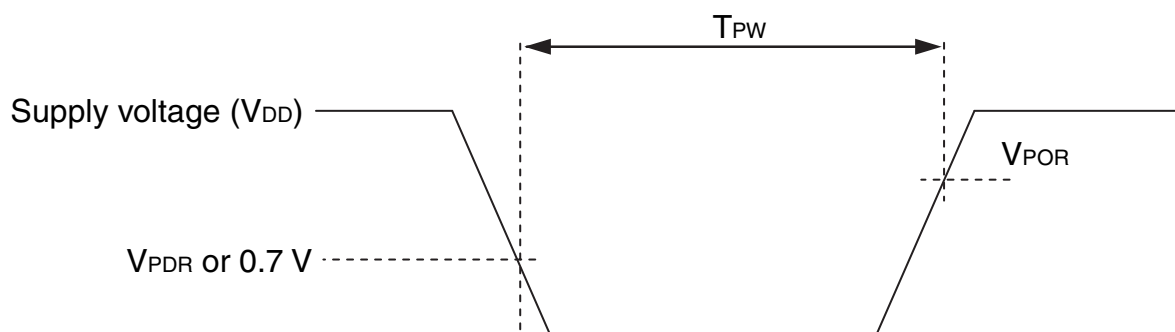
**Note** Cannot be used in subsystem clock operation and STOP mode.

## 3.6.4 POR circuit characteristics

**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection voltage	V <sub>POR</sub>	When power supply rises	1.45	1.51	1.57	V
	V <sub>PDR</sub>	When power supply falls	1.44	1.50	1.56	V
Minimum pulse width <sup>Note</sup>	T <sub>PW</sub>		300			$\mu\text{s}$

**Note** This is the time required for the POR circuit to execute a reset operation when  $V_{DD}$  falls below  $V_{PDR}$ . When the microcontroller enters STOP mode and when the main system clock ( $f_{\text{MAIN}}$ ) has been stopped by setting bit 0 (HIOSTOP) and bit 7 (MSTOP) of the clock operation status control register (CSC), this is the time required for the POR circuit to execute a reset operation between when  $V_{DD}$  falls below  $0.7\text{ V}$  and when  $V_{DD}$  rises to  $V_{POR}$  or higher.



**(2) 1/4 bias method****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
LCD output voltage variation range	V <sub>L1</sub>	C1 to C5 <sup>Note 1</sup> = 0.47 μF <sup>Note 2</sup>	VLCD = 04H	0.90	1.00	1.08	V
			VLCD = 05H	0.95	1.05	1.13	V
			VLCD = 06H	1.00	1.10	1.18	V
			VLCD = 07H	1.05	1.15	1.23	V
			VLCD = 08H	1.10	1.20	1.28	V
			VLCD = 09H	1.15	1.25	1.33	V
			VLCD = 0AH	1.20	1.30	1.38	V
Doubler output voltage	V <sub>L2</sub>	C1 to C5 <sup>Note 1</sup> = 0.47 μF	2 V <sub>L1</sub> – 0.08	2 V <sub>L1</sub>	2 V <sub>L1</sub>	V	
Tripler output voltage	V <sub>L3</sub>	C1 to C5 <sup>Note 1</sup> = 0.47 μF	3 V <sub>L1</sub> – 0.12	3 V <sub>L1</sub>	3 V <sub>L1</sub>	V	
Quadruply output voltage	V <sub>L4</sub>	C1 to C5 <sup>Note 1</sup> = 0.47 μF	4 V <sub>L1</sub> – 0.16	4 V <sub>L1</sub>	4 V <sub>L1</sub>	V	
Reference voltage setup time <sup>Note 2</sup>	t <sub>VWAIT1</sub>		5			ms	
Voltage boost wait time <sup>Note 3</sup>	t <sub>VWAIT2</sub>	C1 to C5 <sup>Note 1</sup> = 0.47 μF	500			ms	

**Notes** 1. This is a capacitor that is connected between voltage pins used to drive the LCD.

C1: A capacitor connected between CAPH and CAPL

C2: A capacitor connected between  $V_{L1}$  and GNDC3: A capacitor connected between  $V_{L2}$  and GNDC4: A capacitor connected between  $V_{L3}$  and GNDC5: A capacitor connected between  $V_{L4}$  and GNDC1 = C2 = C3 = C4 = C5 =  $0.47\ \mu\text{F} \pm 30\%$ 

2. This is the time required to wait from when the reference voltage is specified by using the VLCD register (or when the internal voltage boosting method is selected (by setting the MDSET1 and MDSET0 bits of the LCDM0 register to 01B) if the default value reference voltage is used) until voltage boosting starts (VLCON = 1).

3. This is the wait time from when voltage boosting is started (VLCON = 1) until display is enabled (LCDON = 1).

**3.7.3 Capacitor split method****(1) 1/3 bias method****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_D \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
$V_{L4}$ voltage	$V_{L4}$	C1 to C4 = $0.47\ \mu\text{F}$ <sup>Note 2</sup>		$V_{DD}$		V
$V_{L2}$ voltage	$V_{L2}$	C1 to C4 = $0.47\ \mu\text{F}$ <sup>Note 2</sup>	$\frac{2}{3} V_{L4} - 0.1$	$\frac{2}{3} V_{L4}$	$\frac{2}{3} V_{L4} + 0.1$	V
$V_{L1}$ voltage	$V_{L1}$	C1 to C4 = $0.47\ \mu\text{F}$ <sup>Note 2</sup>	$\frac{1}{3} V_{L4} - 0.1$	$\frac{1}{3} V_{L4}$	$\frac{1}{3} V_{L4} + 0.1$	V
Capacitor split wait time <sup>Note 1</sup>	$t_{VWAIT}$		100			ms

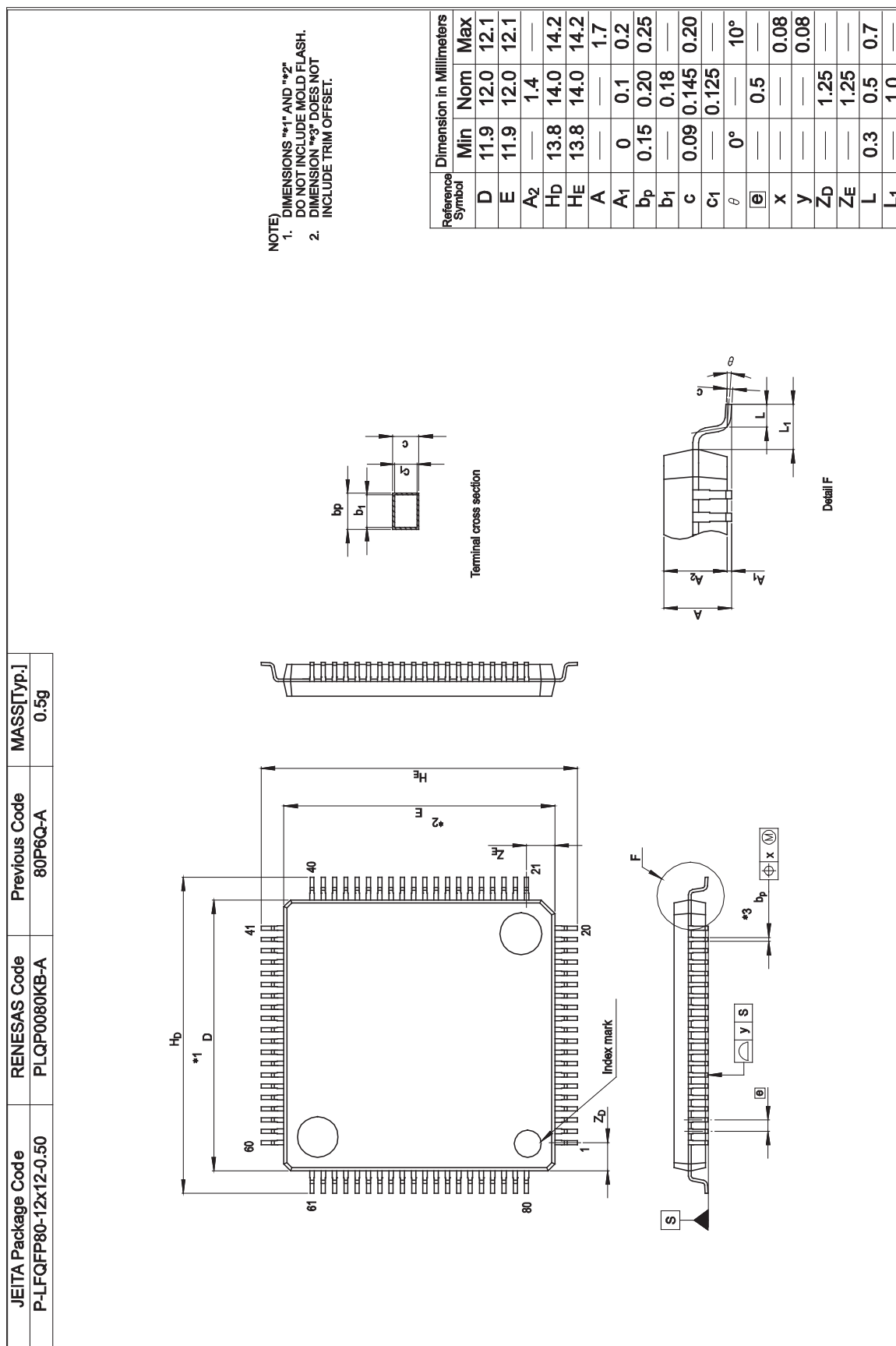
**Notes** 1. This is the wait time from when voltage bucking is started (VLCON = 1) until display is enabled (LCDON = 1).

2. This is a capacitor that is connected between voltage pins used to drive the LCD.

C1: A capacitor connected between CAPH and CAPL

C2: A capacitor connected between  $V_{L1}$  and GNDC3: A capacitor connected between  $V_{L2}$  and GNDC4: A capacitor connected between  $V_{L4}$  and GNDC1 = C2 = C3 = C4 =  $0.47\ \mu\text{F} \pm 30\%$

R5F10WMAAFB, R5F10WMCAFB, R5F10WMDAFB, R5F10WMEAFB, R5F10WMFAFB, R5F10WMGAFB,  
R5F10WMAGFB, R5F10WMCGB, R5F10WMDGB, R5F10WMEGB, R5F10WMFGB, R5F10WMGGB



<b>Revision History</b>	<b>RL78/L13 Data Sheet</b>
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Rev.	Date	Description	
		Page	Summary
0.01	Apr 13, 2012	-	First Edition issued
0.02	Oct 31, 2012	-	Change of the number of segment pins • 64-pin products: 36 pins • 80-pin products: 51 pins
2.10	Aug 12, 2016	1	Modification of features of 16-bit timer and 16-bit timer KB20 (IH) in 1.1 Features
		5	Addition of product name (RL78/L13) and description (Top View) in 1.3.1 64-pin products
		6	Addition of product name (RL78/L13) and description (Top View) in 1.3.2 80-pin products
		10	Modification of functional overview of main system clock in 1.6 Outline of Functions
		15	Modification of description in Absolute Maximum Ratings (3/3)
		17, 18	Modification of description in 2.3.1 Pin characteristics
		38	Modification of remark 3 in 2.5.1 (4) During communication at same potential (simplified I <sup>2</sup> C mode)
		68	Modification of the title and note, and addition of caution in 2.8 RAM Data Retention Characteristics
		70	Addition of Remark
		74	Modification of description in Absolute Maximum Ratings (T <sub>A</sub> = 25 °C) (3/3)
		76	Modification of description in 3.3.1 Pin characteristics
		95	Modification of remark 3 in 3.5.1 (4) During communication at same potential (simplified I <sup>2</sup> C mode)
		118	Modification of the title and note, and addition of caution in 3.8 RAM Data Retention Characteristics

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